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Serial No. 09/960,398

Group Art Unit: 2813
Examiner: **Chandra P. Chaudhari**

INFORMATION DISCLOSURE CITATION PTO-1449	Atty. Docket No. 011254	Serial No. 09/960,398
	Applicant(s): Masaki KURASAWA et al.	
	Filing Date: September 24, 2001	Group Art Unit: 2813

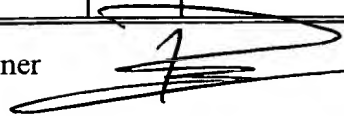
U.S. PATENT DOCUMENTS

Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
_____	AA					
_____	AB					
_____	AC					

FOREIGN PATENT DOCUMENTS

Document No.	Date	Country	Translation (Yes or No)
<u>72</u> AD JP Hei 06-151601 (A)	5/31/94	Japan	Abstract
<u>72</u> AE JP Hei 06-151602 (A)	5/31/94	Japan	Abstract
<u>82</u> AF			
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OTHER DOCUMENTS

<u>72</u> AH	Y. Sakashita et al., J. Appl. Phys. 69, 8352-8357 (1991) "Preparation and Electrical Properties of MOCVD-Deposited PZT Thin Films"
<u>72</u> AI	J.F.Scott et al., J. Appl. Phys. 70, 382-388 (1991) "Quantitative Measurement of Space-Charge Effects in Lead Zirconate-Titanate Memories"
<u>72</u> AJ	M.H. Kim et al., J. Mater. Res. 14, 634-637 (1999) "Highly (200)-Oriented Pt Films on SiO ₂ /Si Substrates By Seed Selection Through Amorphization and Controlled Grain Growth"
Examiner 	Date Considered 6 Aug-02